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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Complete if Known				
Application Number	09/973,814			
Confirmation Number	7822			
Filing Date	October 11, 2001			
First Named Inventor	Toshiaki KUNIYASU			
Art Unit	2881			
Examiner Name	NOT YET ASSIGNED			
Attorney Docket Number	Q66676			

	U.S. PATENT DOCUMENTS						
Examiner Initials*	C'A-	Document	Number	Publication Date MM-DD-YYYY			
	Cite No. ¹	Number	Kind Code ² (if known)		Name of Patentee or Applicant of Cited Document		
	//	US 6,127,691	A	10/03/00	FUKUNAGA, et al		
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	FOREIGN PATENT DOCUMENTS						
Examiner Cite Initials* No.1	Foreign Patent Document			Publication Date	Name of Patentee or		
	Country Code ³	Number ⁴	Kind Code ⁵ (if known)	MM-DD-YYYY	Applicant of Cited Document	Translation ⁶	
		ЛР	11-220224		08/10/99		
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		OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation ⁶
		FUKUNAGA, et al "High-Power 0.8 μm InGaAsP/InGaP/A1GaAs Single Quantum Well :Lasers with Tensile-Strained InGaP Barriers" Jpn. J. Appl. Phys. Vol.38 (1999) pp. L387-L389 Part 2, No. 4A, 1 April 1999	
70		HORIE, et al "Thermal Rollover Characteristics Up to 150 °C of Buiried-Stripe Type 980-nm Laser Diodes with a Current Injection Window Delineated by a SiNχ Layer" IEEE Photonics Technology Letters, Vol. 12, No. 1, January 2000, pp. 13-15	
			

Examiner Signature Date Considered 40403

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